

**2SC3772**

UHF Oscillator, Mixer, Low-Noise Amplifier, Wide-Band Amplifier Applications

Applications

- UHF frequency converters, local oscillators, low-noise amplifiers, wide-band amplifiers.

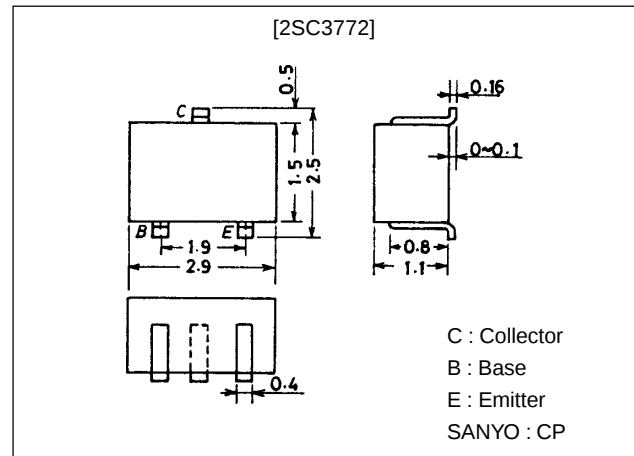
Features

- Small noise figure : NF=2.5dB typ (f=0.9GHz).
- High power gain : MAG=12dB typ (f=0.9GHz).
- High cutoff frequency : $f_T=3.0\text{GHz}$ typ.

Package Dimensions

unit:mm

2018A



Specifications

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		25	V
Collector-to-Emitter Voltage	V_{CEO}		16	V
Emitter-to-Base Voltage	V_{EBO}		3	V
Collector Current	I_C		70	mA
Base Current	I_B		20	mA
Collector Dissipation	P_C		250	mW
Junction Temperature	T_J		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=16\text{V}, I_E=0$			1.0	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=2\text{V}, I_C=0$			10	μA
DC Current Gain	h_{FE}	$V_{CE}=10\text{V}, I_C=10\text{mA}$	40*		200*	
Gain-Bandwidth Product	f_T	$V_{CE}=10\text{V}, I_C=10\text{mA}$	1.5	3.0		GHz
Output Capacitance	C_{ob}	$V_{CB}=10\text{V}, f=1\text{MHz}$		0.65	1.0	pF
Reverse Transfer Capacitance	C_{re}	$V_{CB}=10\text{V}, f=1\text{MHz}$		0.45		pF

* : The 2SC3772 is classified by 10mA h_{FE} as follows :

40	2	80	60	3	120	100	4	200
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(Note) Marking : LY

 h_{FE} rank : 2, 3, 4

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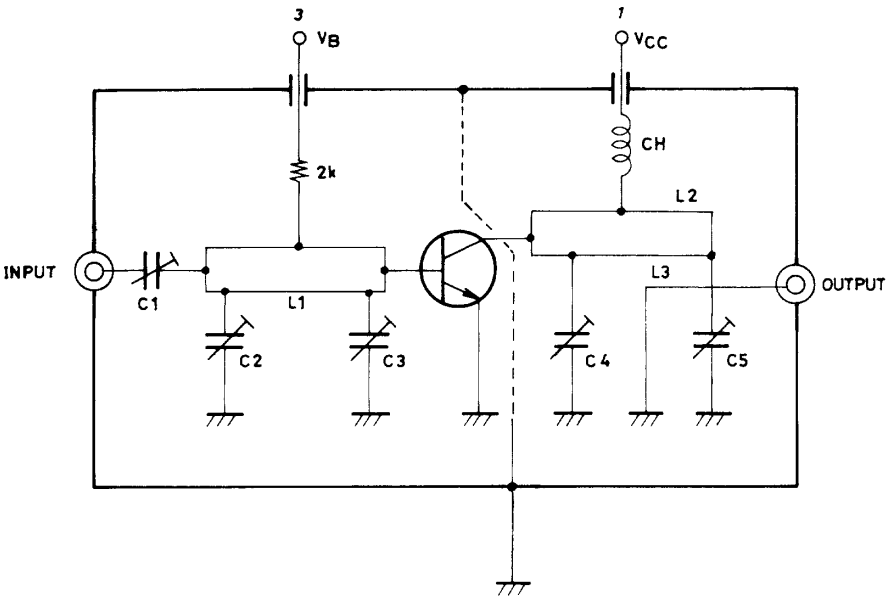
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N3098HA (KT)/5318MO/5137KI/O115KI, TS No.1945-1/5

2SC3772

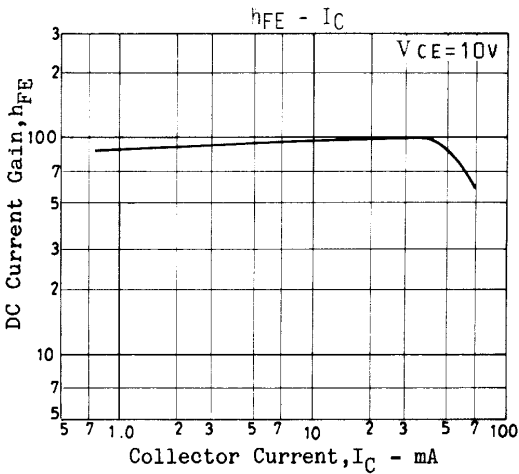
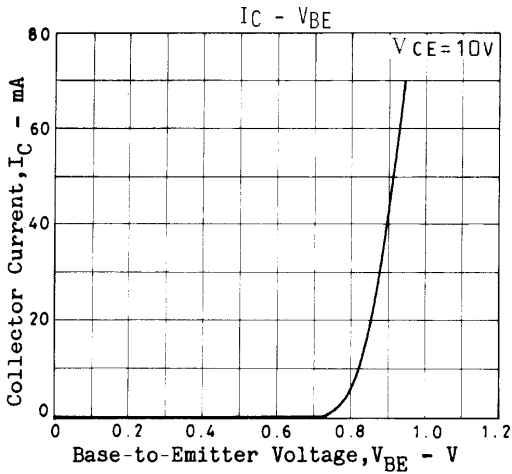
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Forward Transfer Gain	$ S_{21e} ^2$	$V_{CE}=10V, I_C=10mA, f=0.9GHz$	7	9		dB
Maximum Available Power Gain	MAG	$V_{CE}=10V, I_C=10mA, f=0.9GHz$		12		dB
Noise Figure	NF	$V_{CE}=10V, I_C=3mA, f=0.9GHz$, See specified Test Circuit.		2.5		dB

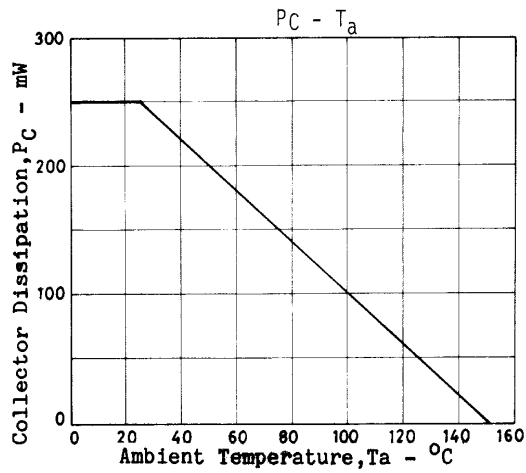
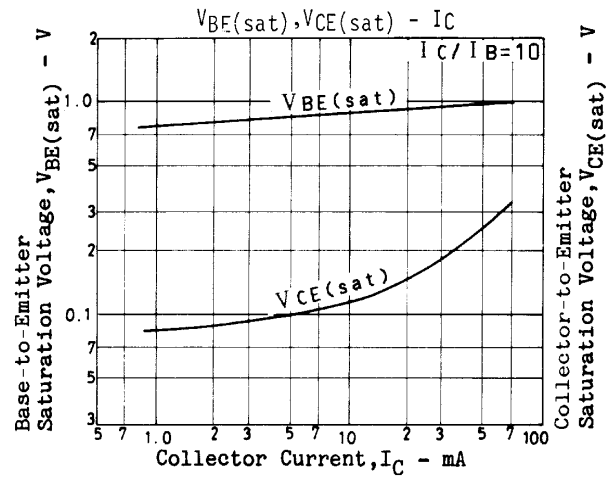
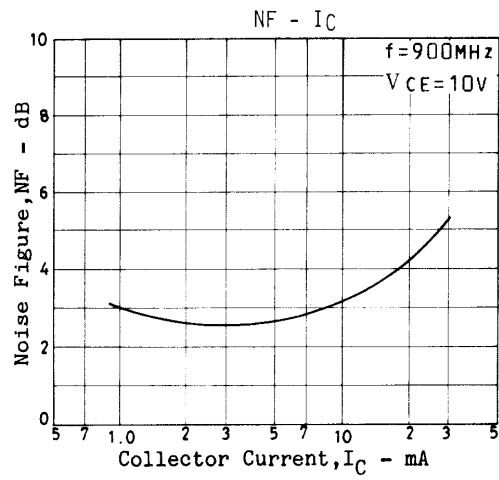
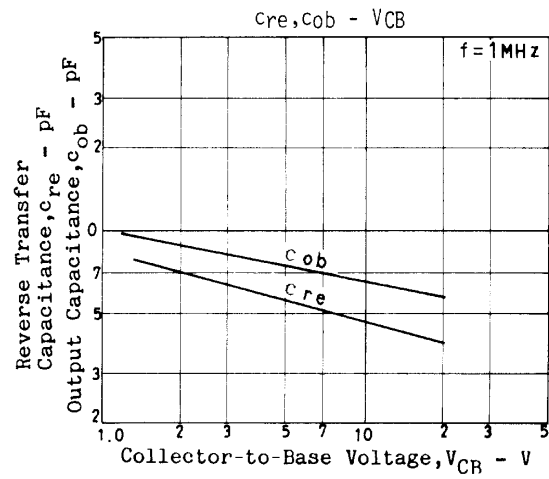
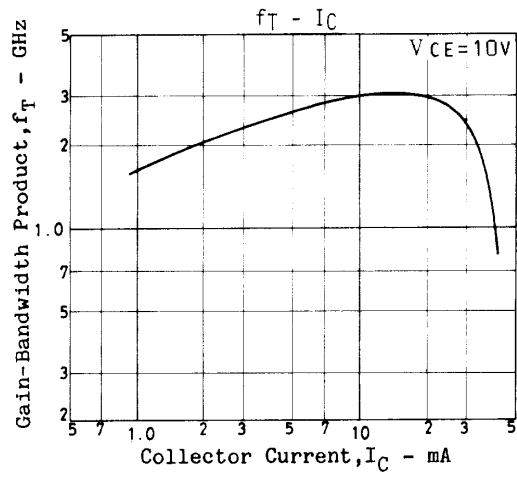
NF Test Circuit



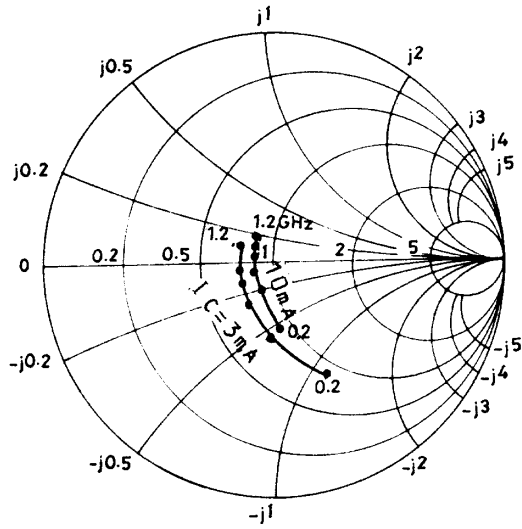
Unit (resistance : Ω)

	900MHz
C1	$\sim 5pF$
C2	$\sim 10pF$
C3	$\sim 10pF$
C4	$\sim 10pF$
C5	$\sim 10pF$
L1	$W \approx 1.5mm, l \approx 25mm$ Strip line
L2	$W \approx 4mm, l \approx 25mm$ Strip line
L3	$0.5\phi, l \approx 40mm$
CH	2t+bead core

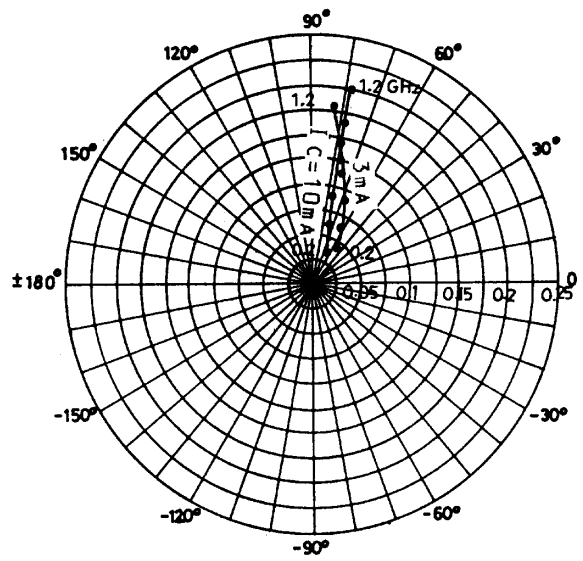




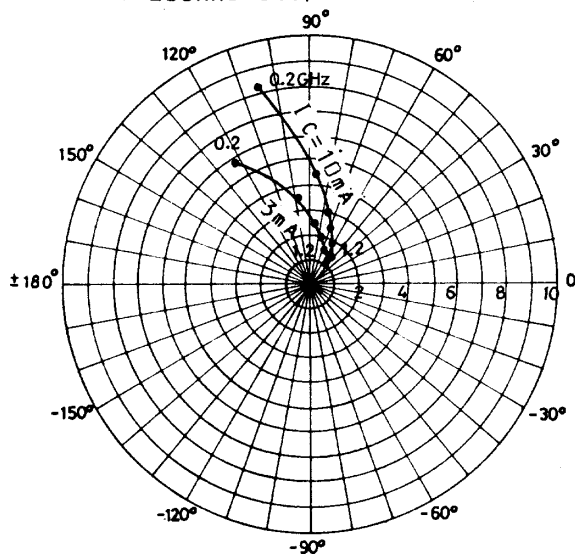
S11e : $V_{CE}=10V$
f=200MHz step



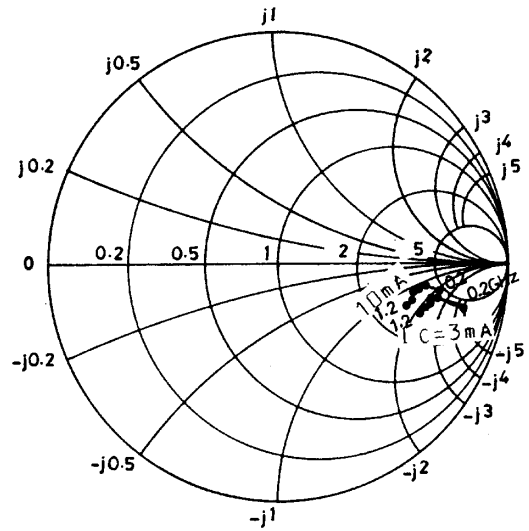
S12e : $V_{CE}=10V$
f=200MHz step



S21e : $V_{CE}=10V$
f=200MHz step



S22e : $V_{CE}=10V$
f=200MHz step



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